### Single, Dual, Quad Low-Voltage, Rail-to-Rail Operational Amplifiers

### LMV321, NCV321, LMV358, LMV324

The LMV321, LMV321I, NCV321, LMV358/LMV358I and LMV324 are CMOS single, dual, and quad low voltage operational amplifiers with rail-to-rail output swing. These amplifiers are a cost-effective solution for applications where low power consumption and space saving packages are critical. Specification tables are provided for operation from power supply voltages at 2.7 V and 5 V. Rail-to-Rail operation provides improved signal-to-noise preformance. Ultra low quiescent current makes this series of amplifiers ideal for portable, battery operated equipment. The common mode input range includes ground making the device useful for low-side current-shunt measurements. The ultra small packages allow for placement on the PCB in close proximity to the signal source thereby reducing noise pickup.

#### Features

- Operation from 2.7 V to 5.0 V Single–Sided Power Supply
- LMV321 Single Available in Ultra Small 5 Pin SC70 Package
- No Output Crossover Distortion
- Rail-to-Rail Output
- Low Quiescent Current: LMV358 Dual 220 μA, Max per Channel
- No Output Phase-Reversal from Overdriven Input
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

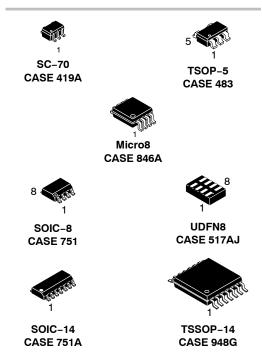
#### **Typical Applications**

- Notebook Computers and PDA's
- Portable Battery-Operated Instruments
- Active Filters



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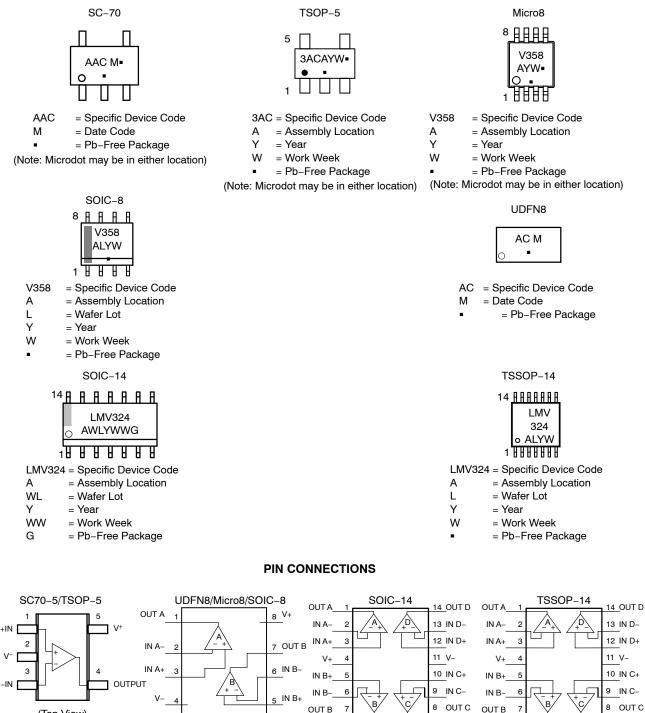
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ORDERING AND MARKING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

#### MARKING DIAGRAMS



(Top View)

(Top View)

(Top View)

(Top View)

#### MAXIMUM RATINGS

| Symbol           | Rating  | Value                                 | Unit     |
|------------------|---|---------------------------------------|----------|
| VS               | Supply Voltage (Operating Range $V_S$ = 2.7 V to 5.5 V)   | 5.5                                   | V        |
| V <sub>IDR</sub> | Input Differential Voltage  | $\pm$ Supply Voltage                  | V        |
| VICR             | Input Common Mode Voltage Range   | -0.5 to (V+) + 0.5                    | V        |
|                  | Maximum Input Current   | 10                                    | mA       |
| t <sub>So</sub>  | Output Short Circuit (Note 1)   | Continuous                            |          |
| TJ               | Maximum Junction Temperature  | 150                                   | °C       |
| T <sub>A</sub>   | Operating Ambient Temperature Range<br>LMV321, LMV358, LMV324<br>LMV321I, LMV358I<br>NCV321 (Note 2)  | -40 to 85<br>-40 to 125<br>-40 to 125 | ဝံ ဝံ ဝံ |
| $\theta_{JA}$    | Thermal Resistance:   |                                       | °C/W     |
|                  | SC-70   | 280                                   |          |
|                  | Micro8  | 238                                   |          |
|                  | TSOP-5  | 333                                   |          |
|                  | UDFN8 (1.2 mm x 1.8 mm x 0.5 mm)  | 350                                   |          |
|                  | SOIC-8  | 212                                   |          |
|                  | SOIC-14   | 156                                   |          |
|                  | TSSOP-14  | 190                                   |          |
| T <sub>stg</sub> | Storage Temperature   | –65 to 150                            | °C       |
|                  | Mounting Temperature (Infrared or Convection -20 sec)   | 260                                   | °C       |
| V <sub>ESD</sub> | ESD Tolerance (Note 3)<br>LMV321, LMV321I, NCV321<br>Machine Model<br>Human Body Model<br>LMV358/358I/324<br>Machine Model<br>Human Body Mode | 100<br>1000<br>100<br>2000            | V        |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

 Continuous short-circuit operation to ground at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of 45 mA over long term may adversely affect reliability. Shorting output to either V+ or V- will adversely affect reliability.

2. NCV prefix is qualified for automotive usage.

 Human Body Model, applicable std. MIL-STD-883, Method 3015.7 Machine Model, applicable std. JESD22-A115-A (ESD MM std. of JEDEC) Field-Induced Charge-Device Model, applicable std. JESD22-C101-C (ESD FICDM std. of JEDEC).

2.7 V DC ELECTRICAL CHARACTERISTICS (Unless otherwise specified, all limits are guaranteed for  $T_A = 25^{\circ}C$ ,  $V^+ = 2.7 V$ ,  $R_L = 1 M\Omega, V^- = 0 V, V_O = V+/2)$ 

| Parameter  | Symbol            | Condition   | Min                   | Тур                  | Max               | Unit  |
|--|-------------------|---|-----------------------|----------------------|-------------------|-------|
| Input Offset Voltage   | V <sub>IO</sub>   | $T_A = T_{Low}$ to $T_{High}$ (Note 4)                                    |                       | 1.7                  | 9                 | mV    |
| Input Offset Voltage Average Drift   | ICV <sub>OS</sub> | $T_A = T_{Low}$ to $T_{High}$ (Note 4)                                    |                       | 5                    |                   | μV/°C |
| Input Bias Current   | ۱ <sub>B</sub>    | $T_A = T_{Low}$ to $T_{High}$ (Note 4)                                    |                       | <1                   |                   | nA    |
| Input Offset Current   | I <sub>IO</sub>   | $T_A = T_{Low}$ to $T_{High}$ (Note 4)                                    |                       | <1                   |                   | nA    |
| Common Mode Rejection Ratio  | CMRR              | $0 \text{ V} \leq \text{V}_{\text{CM}} \leq 1.7 \text{ V}$                | 50                    | 63                   |                   | dB    |
| Power Supply Rejection Ratio   | PSRR              | $\begin{array}{l} 2.7 \ V \leq V+ \leq 5 \ V, \\ V_O = 1 \ V \end{array}$ | 50                    | 60                   |                   | dB    |
| Input Common-Mode Voltage Range  | V <sub>CM</sub>   | For CMRR $\geq$ 50 dB   | 0 to 1.7              | -0.2 to 1.9          |                   | V     |
| Output Swing   | V <sub>OH</sub>   | $R_L$ = 10 k $\Omega$ to 1.35 V   | V <sub>CC</sub> – 100 | V <sub>CC</sub> – 10 |                   | mV    |
|  | V <sub>OL</sub>   | $R_L$ = 10 k $\Omega$ to 1.35 V (Note 5)                                  |                       | 60                   | 180               | mV    |
| Supply Current LMV321, NCV321<br>LMV358/LMV358I (Both Amplifiers)<br>LMV324 (4 Amplifiers) | I <sub>CC</sub>   |   |                       | 80<br>140<br>260     | 185<br>340<br>680 | μΑ    |

2.7 V AC ELECTRICAL CHARACTERISTICS (Unless otherwise specified, all limits are guaranteed for  $T_A = 25^{\circ}C$ , V<sup>+</sup> = 2.7 V,  $R_L = 1 M\Omega$ ,  $V^- = 0 V$ ,  $V_O = V+/2$ )

| Parameter                    | Symbol         | Condition               | Min | Тур | Max | Unit   |
|------------------------------|----------------|-------------------------|-----|-----|-----|--------|
| Gain Bandwidth Product       | GBWP           | C <sub>L</sub> = 200 pF |     | 1   |     | MHz    |
| Phase Margin                 | Θm             |                         |     | 60  |     | 0      |
| Gain Margin                  | G <sub>m</sub> |                         |     | 10  |     | dB     |
| Input-Referred Voltage Noise | e <sub>n</sub> | f = 50 kHz              |     | 50  |     | nV/√Hz |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics for the listed test conditions. 4. For LMV321, LMV358, LMV324:  $T_A = -40^{\circ}C$  to  $+85^{\circ}C$ For LMV3211, LMV3581, NCV321:  $T_A = -40^{\circ}C$  to  $+125^{\circ}C$ . 5. Guaranteed by design and/or characterization.

| 5.0 V DC ELECTRICAL CHARACTERISTICS (Unless otherwise specified, all limits are guaranteed for $T_A = 25^{\circ}C$ , V <sup>+</sup> = 5.0 V | , |
|---|---|
| $R_{L} = 1 M\Omega, V^{-} = 0 V, V_{O} = V + /2)$   |   |

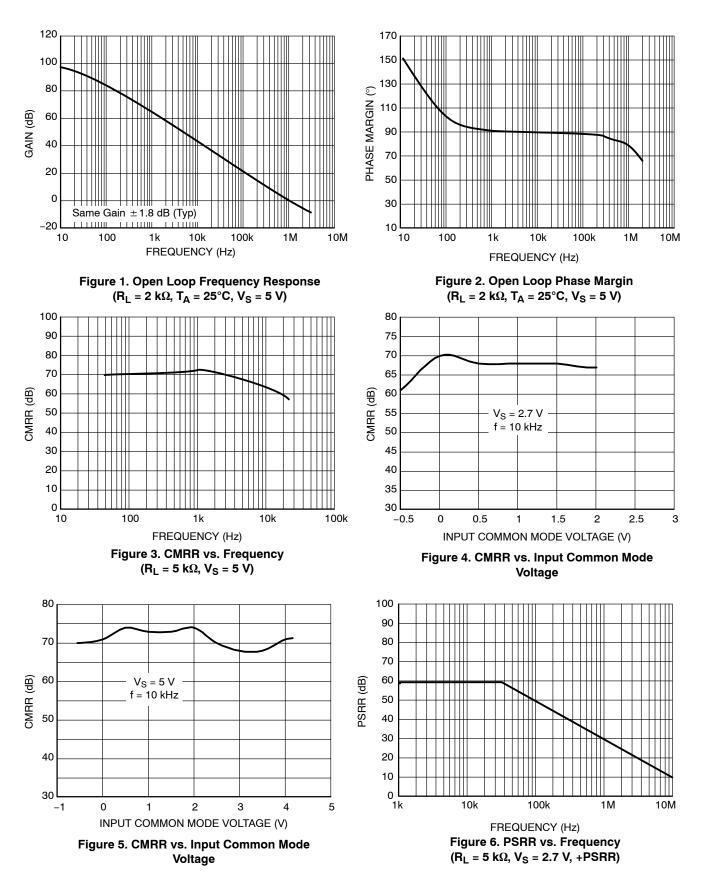
| Parameter                          | Symbol                         | Condition   | Min  | Тур                  | Max         | Unit  |
|------------------------------------|--------------------------------|---|--|----------------------|-------------|-------|
| Input Offset Voltage               | V <sub>IO</sub>                | T <sub>A</sub> = T <sub>Low</sub> to T <sub>High</sub> (Note 6)   |  | 1.7                  | 9           | mV    |
| Input Offset Voltage Average Drift | T <sub>C</sub> V <sub>IO</sub> | T <sub>A</sub> = T <sub>Low</sub> to T <sub>High</sub> (Note 6)   |  | 5                    |             | μV/°C |
| Input Bias Current (Note 7)        | Ι <sub>Β</sub>                 | T <sub>A</sub> = T <sub>Low</sub> to T <sub>High</sub> (Note 6)   |  | < 1                  |             | nA    |
| Input Offset Current (Note 7)      | I <sub>IO</sub>                | T <sub>A</sub> = T <sub>Low</sub> to T <sub>High</sub> (Note 6)   |  | < 1                  |             | nA    |
| Common Mode Rejection Ratio        | CMRR                           | $0 \text{ V} \leq \text{V}_{\text{CM}} \leq 4 \text{ V}$  | 50   | 65                   |             | dB    |
| Power Supply Rejection Ratio       | PSRR                           | $\begin{array}{l} 2.7 \ \text{V} \leq \text{V}_{+} \leq 5 \ \text{V}, \\ \text{V}_{O} = 1 \ \text{V}, \ \text{V}_{CM} = 1 \ \text{V} \end{array}$                   | 50   | 60                   |             | dB    |
| Input Common-Mode Voltage Range    | V <sub>CM</sub>                | For CMRR $\geq$ 50 dB   | 0 to 4   | -0.2 to 4.2          |             | V     |
| Large Signal Voltage Gain (Note 7) | A <sub>V</sub>                 | $R_L = 2 k\Omega$   | 15   | 100                  |             | V/mV  |
|                                    |                                | $T_A = T_{Low}$ to $T_{High}$ (Note 6)  | 10   |                      |             |       |
| Output Swing                       | V <sub>OH</sub>                | $\begin{array}{l} R_{L} = 2 \; k\Omega \; \text{to} \; 2.5 \; V \\ T_{A} = T_{Low} \; \text{to} \; T_{High} \; (Note \; 6) \end{array}$                             | V <sub>CC</sub> - 300<br>V <sub>CC</sub> - 400 | V <sub>CC</sub> - 40 |             | mV    |
|                                    | V <sub>OL</sub>                | $R_L = 2 k\Omega$ to 2.5 V (Note 7)<br>$T_A = T_{Low}$ to $T_{High}$ (Note 6)   |  | 120                  | 300<br>400  | mV    |
|                                    | V <sub>OH</sub>                | $ \begin{array}{l} R_L = 10 \ \text{k}\Omega \ \text{to} \ 2.5 \ \text{V} \ (\text{Note 7}) \\ T_A = T_{Low} \ \text{to} \ T_{High} \ (\text{Note 6}) \end{array} $ | V <sub>CC</sub> - 100<br>V <sub>CC</sub> - 200 |                      |             | mV    |
|                                    | V <sub>OL</sub>                | $R_L$ = 10 kΩ to 2.5 V<br>T <sub>A</sub> = T <sub>Low</sub> to T <sub>High</sub> (Note 6)   |  | 65                   | 180<br>280  | mV    |
| Output Short Circuit Current       | Ι <sub>Ο</sub>                 | Sourcing = $V_0 = 0 V$ (Note 7)<br>Sinking = $V_0 = 5 V$ (Note 7)   | 10<br>10                                       | 60<br>160            |             | mA    |
| Supply Current                     | ICC                            | LMV321<br>T <sub>A</sub> = T <sub>Low</sub> to T <sub>High</sub> (Note 6)   |  | 130                  | 250<br>350  | μΑ    |
|                                    |                                | NCV321<br>T <sub>A</sub> = T <sub>Low</sub> to T <sub>High</sub> (Note 6)   |  | 130                  | 250<br>350  |       |
|                                    |                                | LMV358/358I Both Amplifiers $T_A = T_{Low}$ to $T_{High}$ (Note 6)  |  | 210                  | 440<br>615  |       |
|                                    |                                | LMV324 All Four Amplifiers $T_A = T_{Low}$ to $T_{High}$ (Note 6)   |  | 410                  | 830<br>1160 |       |

**5.0 V AC ELECTRICAL CHARACTERISTICS** (Unless otherwise specified, all limits are guaranteed for  $T_A = 25^{\circ}C$ , V<sup>+</sup> = 5.0 V,  $R_L$  = 1 MΩ,  $V^-$  = 0 V,  $V_O$  = V+/2)

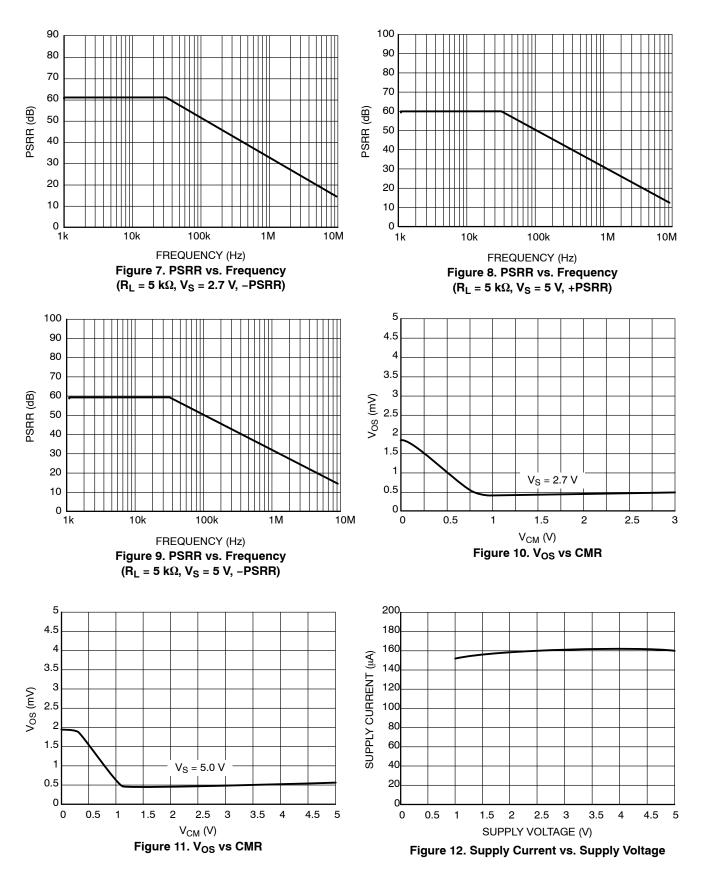
| Parameter                    | Symbol         | Condition               | Min | Тур | Max | Unit               |
|------------------------------|----------------|-------------------------|-----|-----|-----|--------------------|
| Slew Rate                    | S <sub>R</sub> |                         |     | 1   |     | V/µs               |
| Gain Bandwidth Product       | GBWP           | C <sub>L</sub> = 200 pF |     | 1   |     | MHz                |
| Phase Margin                 | Θ <sub>m</sub> |                         |     | 60  |     | 0                  |
| Gain Margin                  | G <sub>m</sub> |                         |     | 10  |     | dB                 |
| Input-Referred Voltage Noise | e <sub>n</sub> | f = 50 kHz              |     | 50  |     | nV/√ <del>Hz</del> |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics for the listed test conditions. 6. For LMV321, LMV358, LMV324:  $T_A = -40^{\circ}C$  to  $+85^{\circ}C$ For LMV3211, LMV3581, NCV321:  $T_A = -40^{\circ}C$  to  $+125^{\circ}C$ . 7. Guaranteed by design and/or characterization.

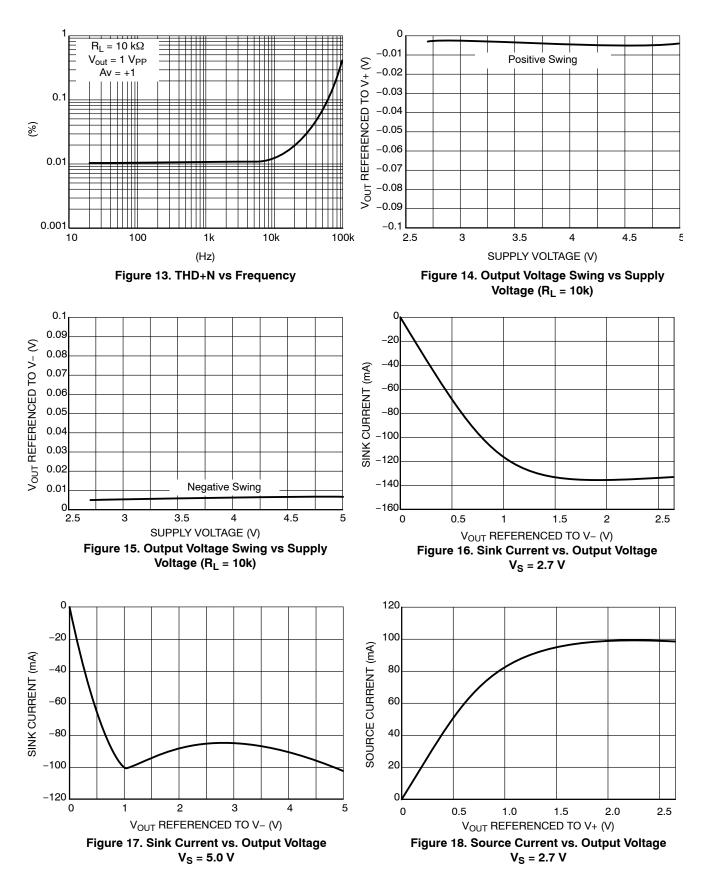
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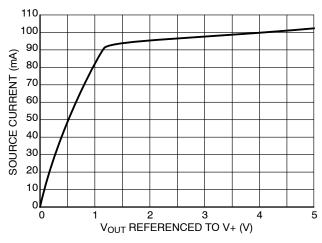
#### **TYPICAL CHARACTERISTICS**

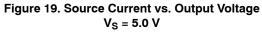


#### **TYPICAL CHARACTERISTICS**



#### **TYPICAL CHARACTERISTICS**





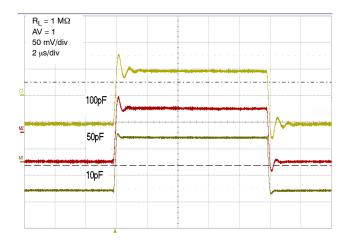


Figure 21. Settling Time vs. Capacitive Load

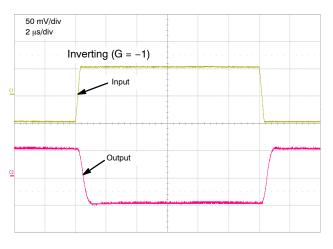


Figure 23. Step Response – Small Signal

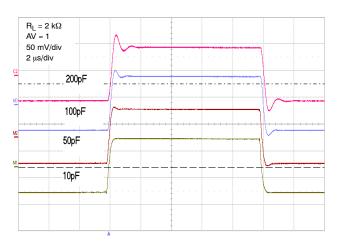


Figure 20. Settling Time vs. Capacitive Load

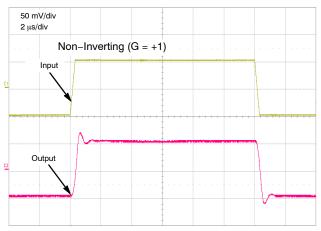
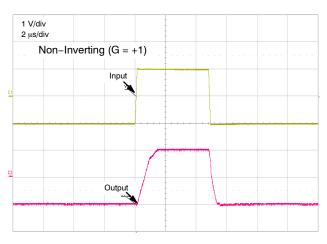


Figure 22. Step Response – Small Signal





#### **TYPICAL CHARACTERISTICS**

(T\_A = 25°C and V\_S = 5 V unless otherwise specified)

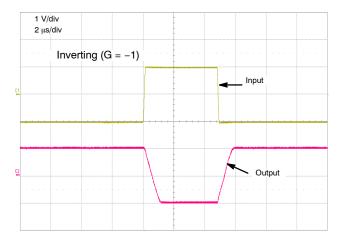
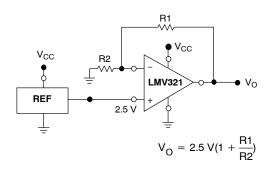
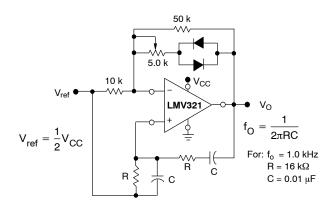


Figure 25. Step Response – Large Signal

#### **APPLICATIONS**









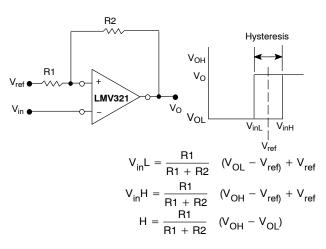
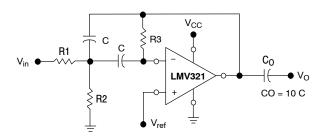
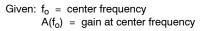


Figure 28. Comparator with Hysteresis





$$\begin{array}{ll} \mbox{Choose value } f_o, C\\ \mbox{Then}: & \mbox{R3} = \frac{Q}{\pi f_O \, C}\\ \mbox{R1} = \frac{R3}{2 \, A(f_O)}\\ \mbox{R2} = \frac{R1 \, R3}{4 Q^2 \, R1 - R3} \end{array}$$

For less than 10% error from operational amplifier, (( $Q_O f_O$ )/BW) < 0.1 where  $f_o$  and BW are expressed in Hz. If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

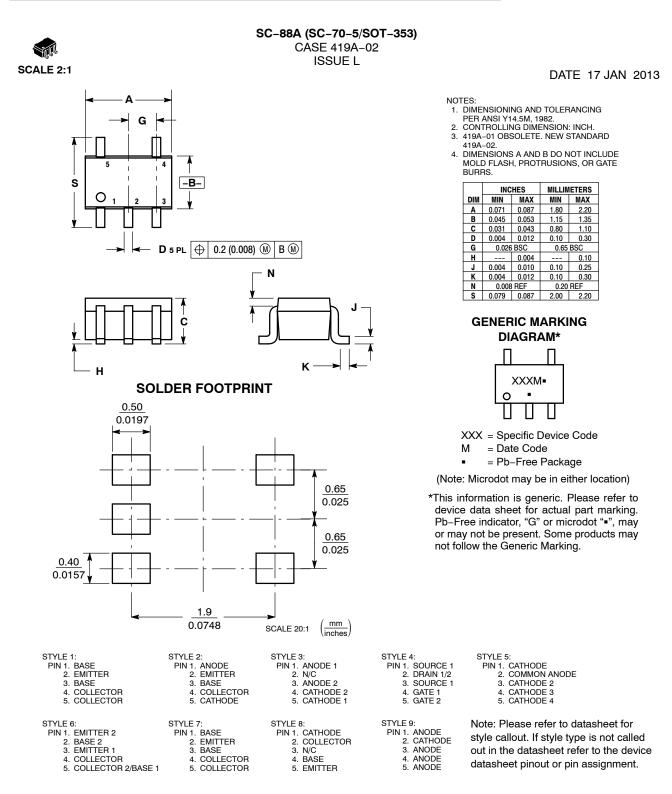
#### Figure 29. Multiple Feedback Bandpass Filter

#### **ORDERING INFORMATION**

| Order Number  | Number<br>of<br>Channels | Specific Device Marking | Package Type          | Shipping <sup>†</sup> |
|---------------|--------------------------|-------------------------|-----------------------|-----------------------|
| LMV321SQ3T2G  | Single                   | AAC                     | SC-70<br>(Pb-Free)    | 3000 / Tape & Reel    |
| LMV321SN3T1G  | Single                   | ЗАС                     | TSOP–5<br>(Pb–Free)   | 3000 / Tape & Reel    |
| LMV321ISN3T1G | Single                   | ЗАС                     | TSOP-5<br>(Pb-Free)   | 3000 / Tape & Reel    |
| NCV321SN3T1G* | Single                   | ЗАС                     | TSOP–5<br>(Pb–Free)   | 3000 / Tape & Reel    |
| LMV358DMR2G   | Dual                     | V358                    | Micro8<br>(Pb–Free)   | 4000 / Tape & Reel    |
| LMV358MUTAG   | Dual                     | AC                      | UDFN8<br>(Pb-Free)    | 3000 / Tape & Reel    |
| LMV358DR2G    | Dual                     | V358                    | SOIC-8<br>(Pb-Free)   | 2500 / Tape & Reel    |
| LMV358IDR2G   | Dual                     | V358                    | SOIC-8<br>(Pb-Free)   | 2500 / Tape & Reel    |
| LMV324DR2G    | Quad                     | LMV324                  | SOIC-14<br>(Pb-Free)  | 2500 / Tape & Reel    |
| LMV324DTBR2G  | Quad                     | LMV<br>324              | TSSOP-14<br>(Pb-Free) | 2500 / Tape & Reel    |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
\*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.



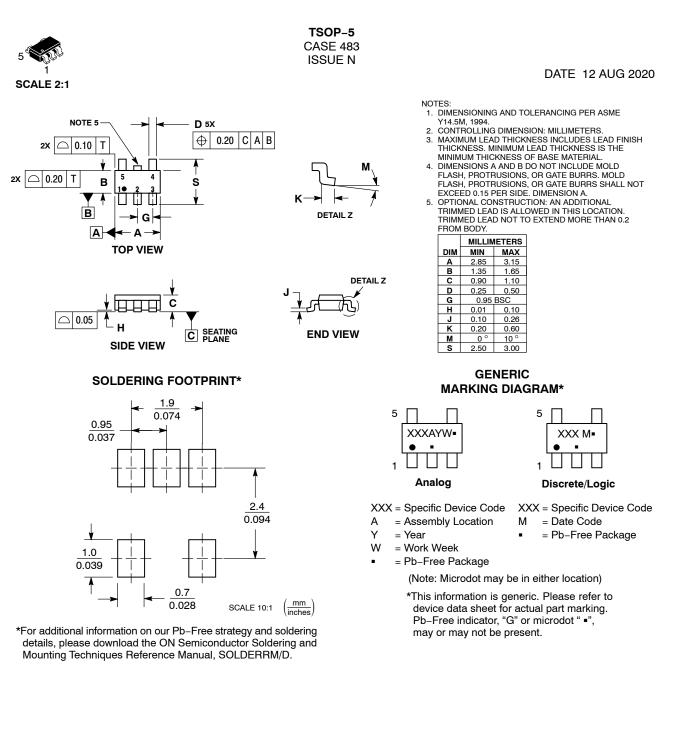


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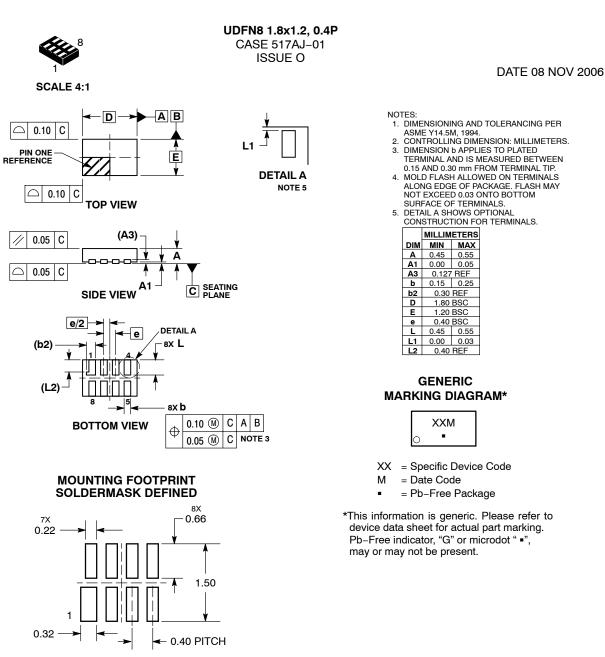
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\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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#### SOIC-8 NB CASE 751-07 ISSUE AK

STYLE 1: PIN 1. EMITTER COLLECTOR 2. 3. COLLECTOR 4. EMITTER 5. EMITTER BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE. DIE #2 BASE, DIE #1 7. 8 EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. DRAIN 8. STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. CATHODE 6 8. STYLE 25: PIN 1. VIN 2 N/C REXT З. 4. GND 5. IOUT IOUT 6. IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2 6.

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. COLLECTOR, #2 4 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: GROUND PIN 1. BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: N-SOURCE PIN 1. 2. N-GATE 3 P-SOURCE P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE ANODE 2. SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. CATHODE 8. STYLE 22 PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3 COMMON CATHODE/VCC 4. I/O LINE 3 COMMON ANODE/GND 5. 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4 SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5. 6.

STYLE 3: DRAIN, DIE #1 PIN 1. DRAIN, #1 2. DRAIN, #2 З. DRAIN, #2 4. 5. GATE, #2 SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. З. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 3 ANODE 1 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. **MIRROR 1** STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. 8. LINE 1 OUT STYLE 27: PIN 1. ILIMIT OVI O 2 З. UVLO 4. INPUT+ 5. 6. SOURCE SOURCE SOURCE 7. 8 DRAIN

## DATE 16 FEB 2011

STYLE 4: PIN 1. 2. ANODE ANODE ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 З. BASE #2 COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. S SOURCE SOURCE 2. 3. GATE 4. 5. DRAIN 6 DRAIN DRAIN 7. 8. DRAIN STYLE 16 EMITTER, DIE #1 PIN 1. 2. BASE, DIE #1 EMITTER DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE EMITTER 2. 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE 6. CATHODE COLLECTOR/ANODE 7. COLLECTOR/ANODE 8. STYLE 28: 11. SW\_TO\_GND 2. DASIC OFF PIN 1. DASIC\_SW\_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK 8 VIN

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SOURCE 1/DRAIN 2

7.

8. GATE 1

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7.

8

COLLECTOR, #1

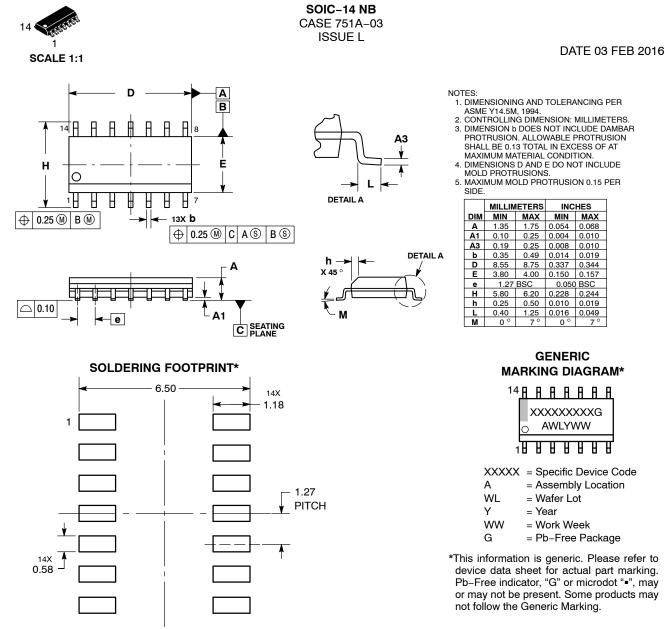
COLLECTOR, #1

## DUSEM

0.068

0.019

0.344



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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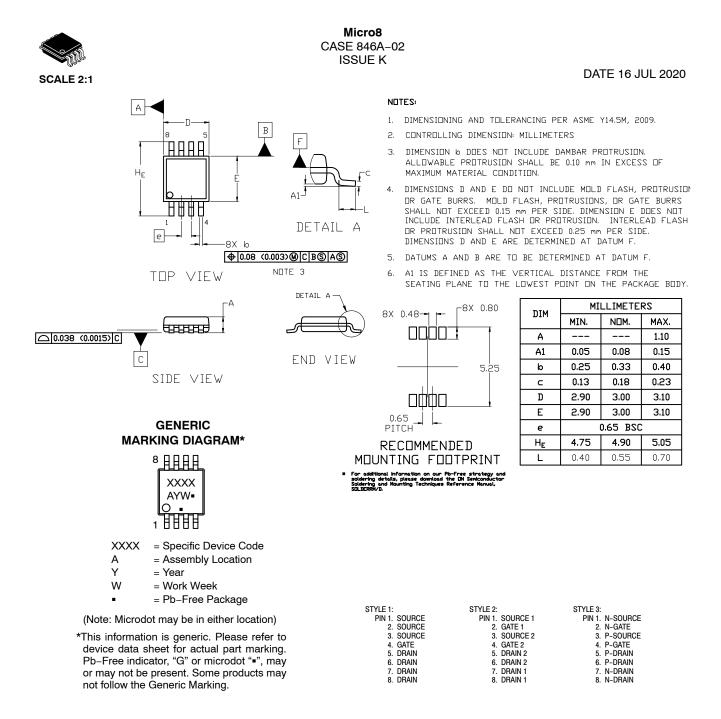
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| STYLE 1:<br>PIN 1. COMMON CATHODE<br>2. ANODE/CATHODE<br>3. ANODE/CATHODE<br>4. NO CONNECTION<br>5. ANODE/CATHODE<br>6. NO CONNECTION<br>7. ANODE/CATHODE<br>8. ANODE/CATHODE<br>9. ANODE/CATHODE<br>10. NO CONNECTION<br>11. ANODE/CATHODE<br>12. ANODE/CATHODE<br>13. NO CONNECTION<br>14. COMMON ANODE | STYLE 2:<br>CANCELLED   | STYLE 3:<br>PIN 1. NO CONNECTION<br>2. ANODE<br>3. ANODE<br>4. NO CONNECTION<br>5. ANODE<br>6. NO CONNECTION<br>7. ANODE<br>8. ANODE<br>9. ANODE<br>10. NO CONNECTION<br>11. ANODE<br>12. ANODE<br>13. NO CONNECTION<br>14. COMMON CATHODE  | STYLE 4:<br>PIN 1. NO CONNECTION<br>2. CATHODE<br>3. CATHODE<br>4. NO CONNECTION<br>5. CATHODE<br>6. NO CONNECTION<br>7. CATHODE<br>8. CATHODE<br>9. CATHODE<br>10. NO CONNECTION<br>11. CATHODE<br>12. CATHODE<br>13. NO CONNECTION<br>14. COMMON ANODE  |
|---|---|---|---|
| STYLE 5:<br>PIN 1. COMMON CATHODE<br>2. ANODE/CATHODE<br>3. ANODE/CATHODE<br>4. ANODE/CATHODE<br>5. ANODE/CATHODE<br>6. NO CONNECTION<br>7. COMMON ANODE<br>8. COMMON CATHODE<br>9. ANODE/CATHODE<br>10. ANODE/CATHODE<br>11. ANODE/CATHODE<br>12. ANODE/CATHODE<br>13. NO CONNECTION<br>14. COMMON ANODE | STYLE 6:<br>PIN 1. CATHODE<br>2. CATHODE<br>3. CATHODE<br>4. CATHODE<br>5. CATHODE<br>6. CATHODE<br>7. CATHODE<br>8. ANODE<br>9. ANODE<br>10. ANODE<br>11. ANODE<br>12. ANODE<br>13. ANODE<br>14. ANODE | STYLE 7:<br>PIN 1. ANODE/CATHODE<br>2. COMMON ANDDE<br>3. COMMON CATHODE<br>4. ANODE/CATHODE<br>5. ANODE/CATHODE<br>6. ANODE/CATHODE<br>7. ANODE/CATHODE<br>9. ANODE/CATHODE<br>10. ANODE/CATHODE<br>11. COMMON CATHODE<br>12. COMMON ANODE<br>13. ANODE/CATHODE<br>14. ANODE/CATHODE | STYLE 8:<br>PIN 1. COMMON CATHODE<br>2. ANODE/CATHODE<br>3. ANODE/CATHODE<br>4. NO CONNECTION<br>5. ANODE/CATHODE<br>6. ANODE/CATHODE<br>7. COMMON ANODE<br>8. COMMON ANODE<br>9. ANODE/CATHODE<br>10. ANODE/CATHODE<br>11. NO CONNECTION<br>12. ANODE/CATHODE<br>13. ANODE/CATHODE<br>14. COMMON CATHODE |

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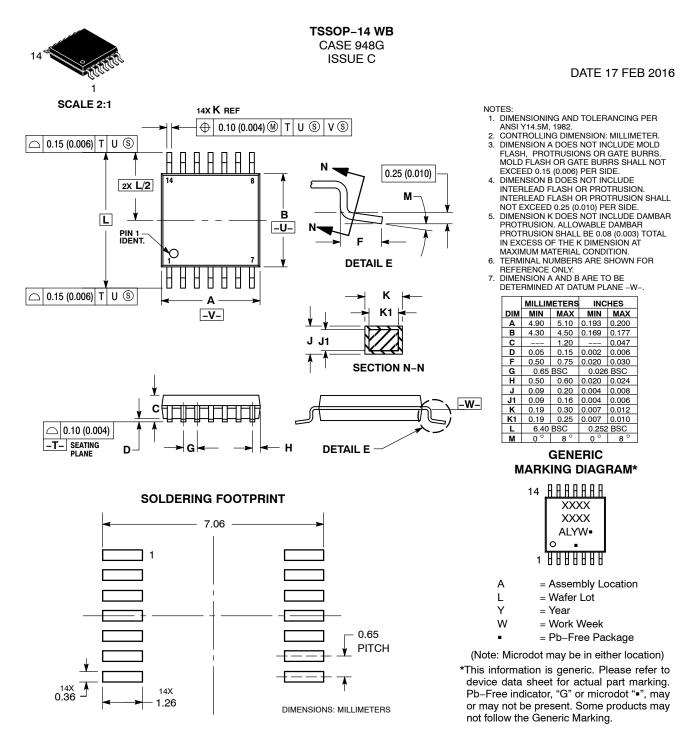




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